

C6D10065A

Silicon Carbide Schottky Diode

Z-REC[®] RECTIFIER

| | | |
|-------------------------------|---|-------|
| V_{RRM} | = | 650 V |
| $I_F (T_c=155^\circ\text{C})$ | = | 10 A |
| Q_c | = | 34 nC |

Features

- New 6th Generation Technology
- Low Forward Voltage Drop (V_F)
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Low Leakage Current (I_L)
- Temperature-Independent Switching Behavior
- Positive Temperature Coefficient on V_F

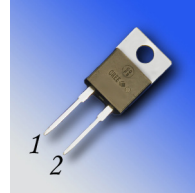
Benefits

- Higher System Level Efficiency
- Increase System Power Density
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies (SMPS)
- Server/Telecom Power Supplies
- Industrial Power Supplies
- Solar
- UPS

Package



TO-220-2



| Part Number | Package | Marking |
|-------------|----------|----------|
| C6D10065A | TO-220-2 | C6D10065 |

Maximum Ratings ($T_c = 25^\circ\text{C}$ unless otherwise specified)

| Symbol | Parameter | Value | Unit | Test Conditions | Note |
|----------------|--|----------------|------------------|---|--------|
| V_{RRM} | Repetitive Peak Reverse Voltage | 650 | V | | |
| V_{DC} | DC Blocking Voltage | 650 | V | | |
| I_F | Continuous Forward Current | 37 19 10 | A | $T_c=25^\circ\text{C}$ $T_c=125^\circ\text{C}$ $T_c=155^\circ\text{C}$ | Fig. 3 |
| I_{FRM} | Repetitive Peak Forward Surge Current | 45 27 | A | $T_c=25^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$ $T_c=110^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$ | |
| I_{FSM} | Non-Repetitive Peak Forward Surge Current | 86 75 | A | $T_c=25^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$ $T_c=110^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$ | Fig. 8 |
| I_{FMax} | Non-Repetitive Peak Forward Surge Current | 1250 1100 | A | $T_c=25^\circ\text{C}, t_p = 10 \mu\text{s}, \text{Pulse}$ $T_c=110^\circ\text{C}, t_p = 10 \mu\text{s}, \text{Pulse}$ | Fig. 8 |
| P_{tot} | Power Dissipation | 109 47 | W | $T_c=25^\circ\text{C}$ $T_c=110^\circ\text{C}$ | Fig. 4 |
| T_J, T_{stg} | Operating Junction and Storage Temperature | -55 to +175 | $^\circ\text{C}$ | | |
| | TO-220 Mounting Torque | 1 8.8 | Nm lbf-in | M3 Screw 6-32 Screw | |

Electrical Characteristics

| Symbol | Parameter | Typ. | Max. | Unit | Test Conditions | Note |
|--------|---------------------------|-----------------|--------------|---------------|--|--------|
| V_F | Forward Voltage | 1.27 1.37 | 1.50 1.60 | V | $I_F = 10\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 10\text{ A}$ $T_J = 175^\circ\text{C}$ | Fig. 1 |
| I_R | Reverse Current | 2 15 | 50 200 | μA | $V_R = 650\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 650\text{ V}$ $T_J = 175^\circ\text{C}$ | Fig. 2 |
| Q_C | Total Capacitive Charge | 34 | | nC | $V_R = 400\text{ V}$, $I_F = 10\text{ A}$ $T_J = 25^\circ\text{C}$ | Fig. 5 |
| C | Total Capacitance | 611 67 53 | | pF | $V_R = 0\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 200\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 400\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ | Fig. 6 |
| E_C | Capacitance Stored Energy | 5.2 | | μJ | $V_R = 400\text{ V}$ | Fig. 7 |

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

| Symbol | Parameter | Typ. | Unit | Note |
|-----------------|--|------|--------------------|--------|
| $R_{\theta JC}$ | Thermal Resistance from Junction to Case | 1.38 | $^\circ\text{C/W}$ | Fig. 9 |

Typical Performance

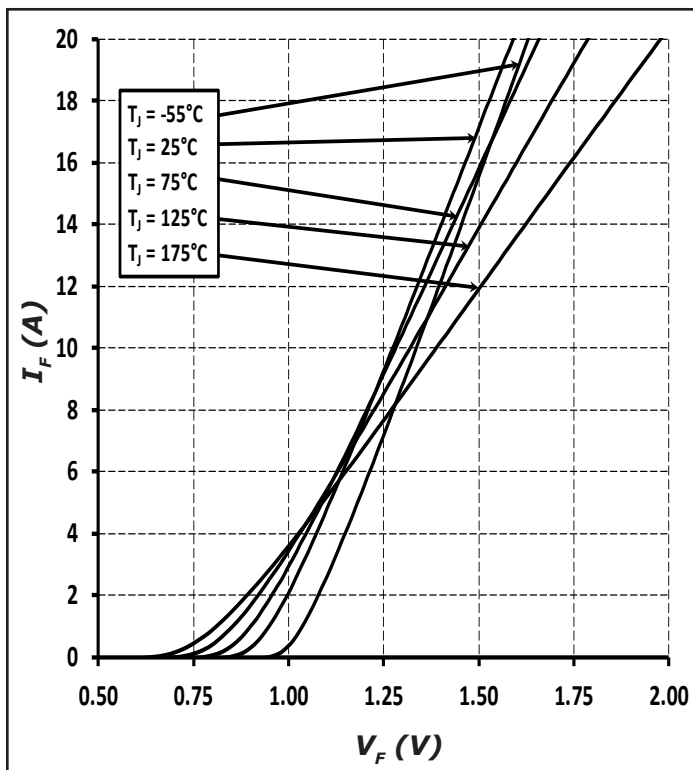


Figure 1. Forward Characteristics

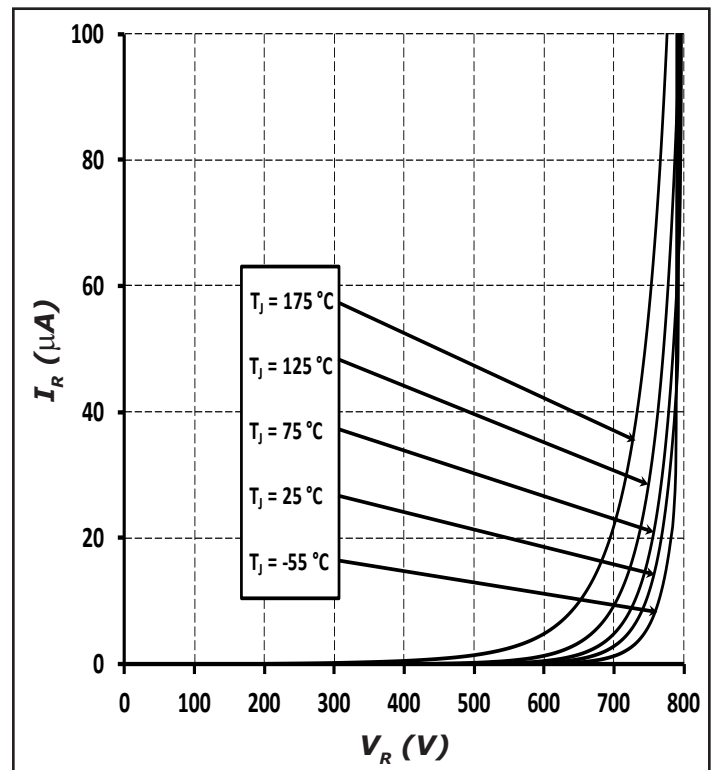


Figure 2. Reverse Characteristics

Typical Performance

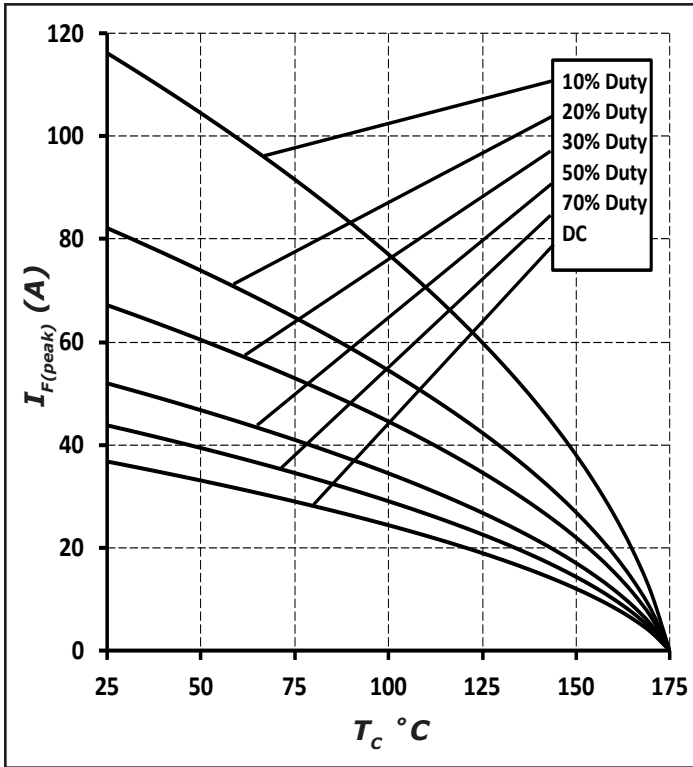


Figure 3. Current Derating

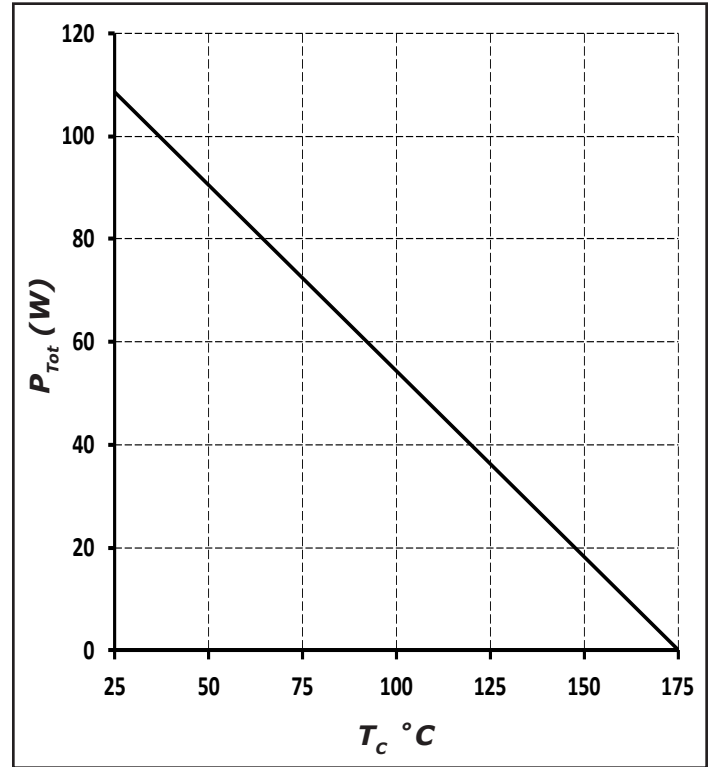


Figure 4. Power Derating

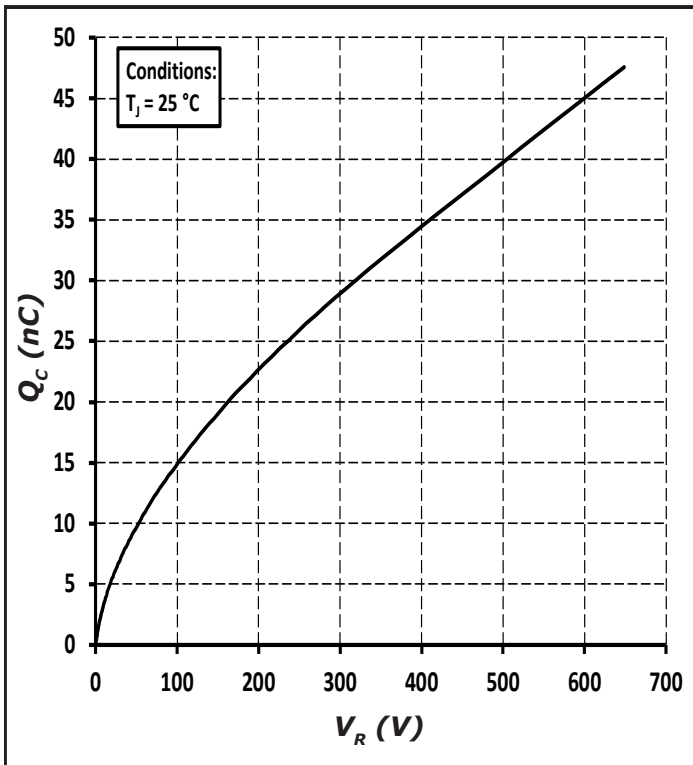


Figure 5. Total Capacitance Charge vs. Reverse Voltage

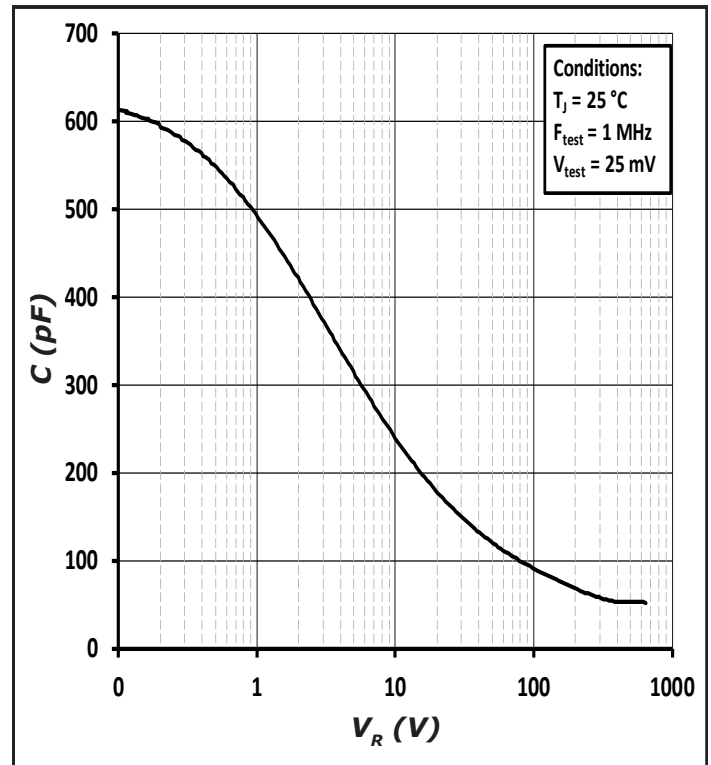


Figure 6. Capacitance vs. Reverse Voltage

Typical Performance

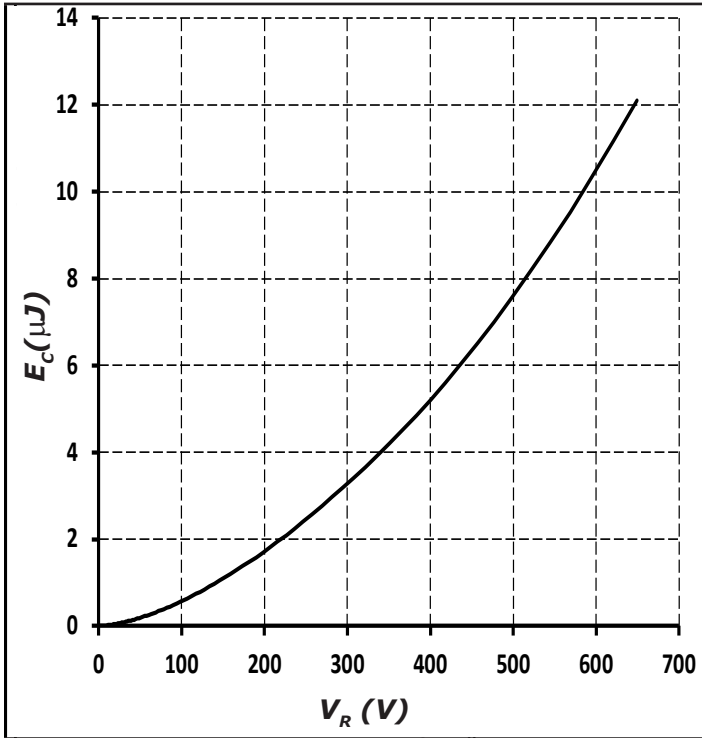


Figure 7. Capacitance Stored Energy

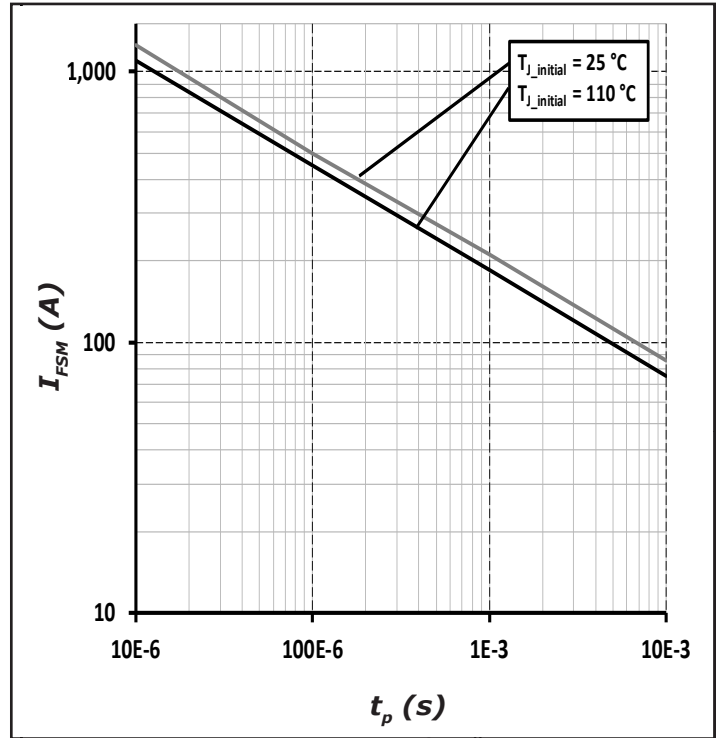


Figure 8. Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

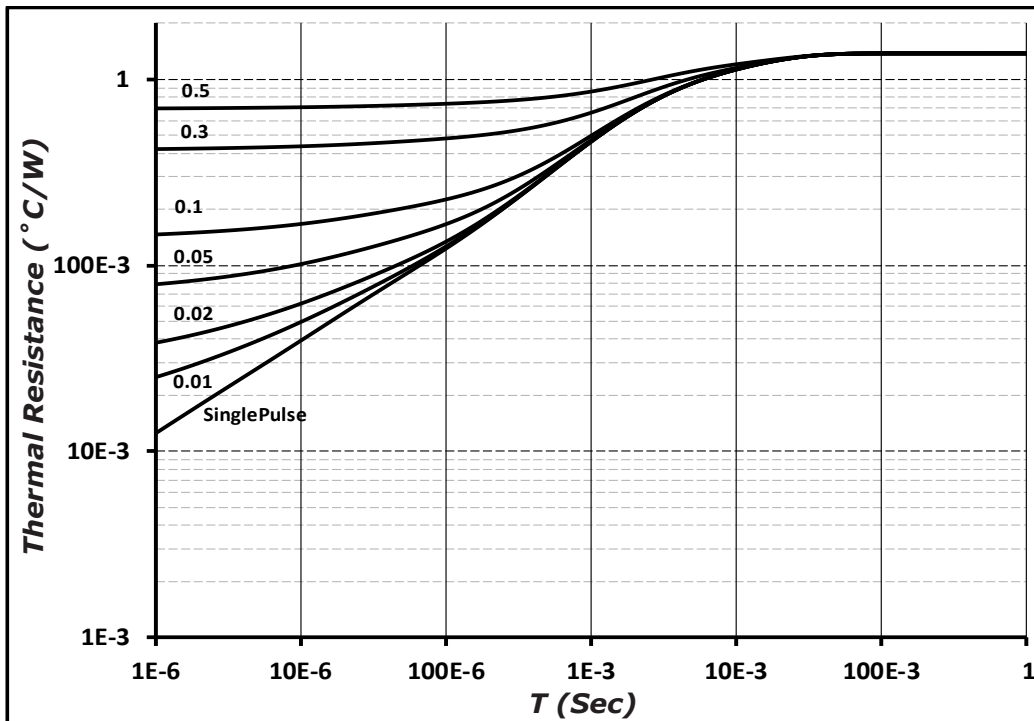
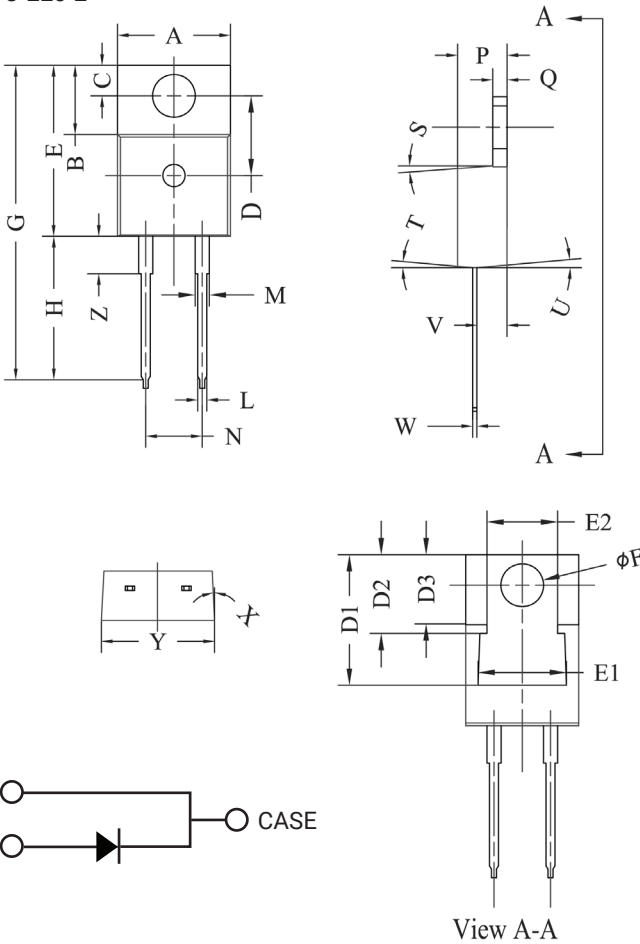


Figure 9. Transient Thermal Impedance

Package Dimensions

Package TO-220-2

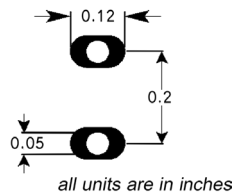


| POS | Inches | | Millimeters | |
|-----|---------------|-------|-----------------|--------|
| | Min | Max | Min | Max |
| A | .381 | .410 | 9.677 | 10.414 |
| B | .235 | .255 | 5.969 | 6.477 |
| C | .100 | .120 | 2.540 | 3.048 |
| D | .223 | .337 | 5.664 | 8.560 |
| D1 | .457-.490 | | 11.60-12.45 typ | |
| D2 | .277-.303 typ | | 7.04-7.70 typ | |
| D3 | .244-.252 typ | | 6.22-6.4 typ | |
| E | .590 | .615 | 14.986 | 15.621 |
| E1 | .302 | .326 | 7.68 | 8.28 |
| E2 | .227 | .251 | 5.77 | 6.37 |
| F | .143 | .153 | 3.632 | 3.886 |
| G | 1.105 | 1.147 | 28.067 | 29.134 |
| H | .500 | .550 | 12.700 | 13.970 |
| L | .025 | .036 | .635 | .914 |
| M | .045 | .055 | 1.143 | 1.550 |
| N | .195 | .205 | 4.953 | 5.207 |
| P | .165 | .185 | 4.191 | 4.699 |
| Q | .048 | .054 | 1.219 | 1.372 |
| S | 3° | 6° | 3° | 6° |
| T | 3° | 6° | 3° | 6° |
| U | 3° | 6° | 3° | 6° |
| V | .094 | .110 | 2.388 | 2.794 |
| W | .014 | .025 | .356 | .635 |
| X | 3° | 5.5° | 3° | 5.5° |
| Y | .385 | .410 | 9.779 | 10.414 |
| Z | .130 | .150 | 3.302 | 3.810 |

NOTE:

1. Dimension L, M, W apply for Solder Dip Finish

Recommended Solder Pad Layout



TO-220-2

| Part Number | Package | Marking |
|-------------|----------|----------|
| C6D10065A | TO-220-2 | C6D10065 |

Note: Recommended soldering profiles can be found in the applications note here:
http://www.wolfspeed.com/power_app_notes/soldering



Notes

- **RoHS Compliance**

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Wolfseed representative or from the Product Ecology section of our website at <http://www.wolfseed.com/Power/Tools-and-Support/Product-Ecology>.

- **REACH Compliance**

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a Cree representative to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

- This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control systems.

Related Links

- Cree SiC Schottky diode portfolio: <http://www.wolfseed.com/Power/Products#SiCSchottkyDiodes>
- Schottky diode Spice models: <http://www.wolfseed.com/power/tools-and-support/DIODE-model-request2>
- SiC MOSFET and diode reference designs: <http://go.pardot.com/l/101562/2015-07-31/349i>



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.